

## **Quarterly Reliability Monitoring Results**

## Quarters: Q1/2022 to Q4/2023

Based on structural similarity

<b>Supplier</b> Nexperia B.V.		User Part Number PBSS9110D						
Nexperia DHAM Small Signal Bipolar Transistor								
SMD package								
Test Conditions	Duration	# Lots	# Quantity	# Rejects				
	TEST							
	Pre- and Post-Stress							
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
		JESD22-A113						
	PC	Bake Tamb = 125 °C	24 hours					
<b>4</b> A 1	Preconditioning	Soak Tamb = 85 °C, RH = 85% Reflow soldering	168 hours 3 cycles	1674	70490	0		
# A1	Treconditioning		5 Cycles	10/4	70490	U		
	HTRB	MIL-STD-750-1 M1039 Method A						
		Tj = Tjmax, Vr = 100% of max. datasheet						
# B1	Bias	reverse voltage	1000 hours	415	18680	0		
<i>"</i> 51		3	1000	.15	10000			
	тс	JESD22-A104						
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	343	15360	0		
	UHAST	JESD22-A118						
# A3 <b>or</b>	Unbiased HAST	Tamb = 130 °C, RH = 85 %	— 96 hours	362	15920	0		
		JESD22-A102						
	AC	Tamb = 121 °C, RH = 100 %						
# A3 alt	Autoclave	Pressure = 205 kPa (29.7 psia)						
		JECD22 4404						
	H3TRB	JESD22-A101 Tamb = 85 °C, RH = 85%, VR = 80 % of						
# A2 - It	High Humidity High Temperature Reverse Bias		1000	242	15260	0		
# A2 alt	Temperature Reverse Bias		1000 hours	343	15360	0		
	IOL	MIL-STD-750 Method 1037 ton = toff, devices powered to insure $\Delta T_j$ =						
# A5	Intermittent Operating Life		1000 hours	343	15360	0		
,, 113			1000 1100/15	545	13300			
	RSH	JESD22-A111						
# C8	Resistance to Solder Heat		10 s	283	8490	0		
	SD							
# C10	Solderability	J-STD-002		214	6420	0		

<sup>[1]</sup> The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia	Small Signal Bipolar				
DHAM	Transistor	18680	0	0,23	4,40E+09

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